

# SANYO Semiconductors DATA SHEET

# MCH3220 — NPN Epitaxial Planar Silicon Transistor

## **DC / DC Converter Applications**

### **Applications**

· Relay drivers, lamp drivers, motor drivers, flash.

#### **Features**

- · Adoption of MBIT processes.
- · Large current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High-speed switching.
- Narrow hFE range.
- Ultrasmall package facilitates miniaturization in end products (mounting height: 0.85mm).
- · High allowable power dissipation.

#### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		15	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	Ic		3	Α
Collector Current (Pulse)	ICP		6	Α
Base Current	IΒ		600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm²X0.8mm)	0.8	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Cymbol		min	typ	max	Oille
Collector Cutoff Current	ICBO	VCB=12V, IE=0A			0.1	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			0.1	μΑ
DC Current Gain	hFE	VCE=2V, IC=500mA	250		400	
Gain-Bandwidth Product	fŢ	V <sub>CE</sub> =2V, I <sub>C</sub> =500mA		380		MHz

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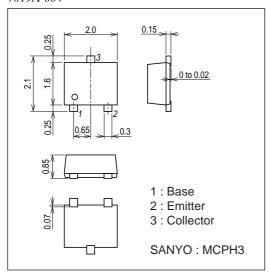
#### MCH3220

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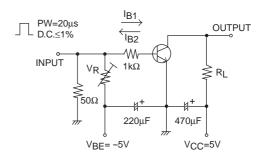
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol	Conditions	min	typ	max	Offic
Output Capacitance	Cob	VCB=10V, f=1MHz		23		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)1	I <sub>C</sub> =1.5A, I <sub>B</sub> =30mA		70	105	mV
	VCE(sat)2	IC=3A, IB=60mA		120	180	mV
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	IC=1.5A, IB=30mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0A	15			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	15			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0A	6			V
Turn-ON Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg	See specified Test Circuit.		210		ns
Fall Time	tf	See specified Test Circuit.		11		ns

#### **Package Dimensions**

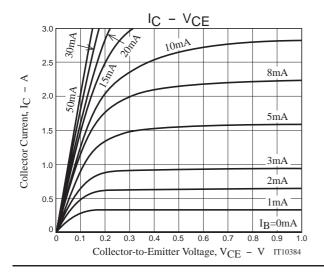
unit : mm 7019A-004

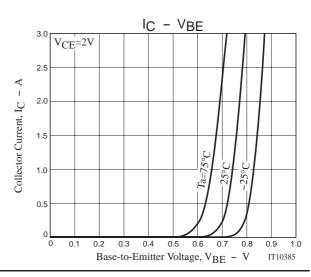


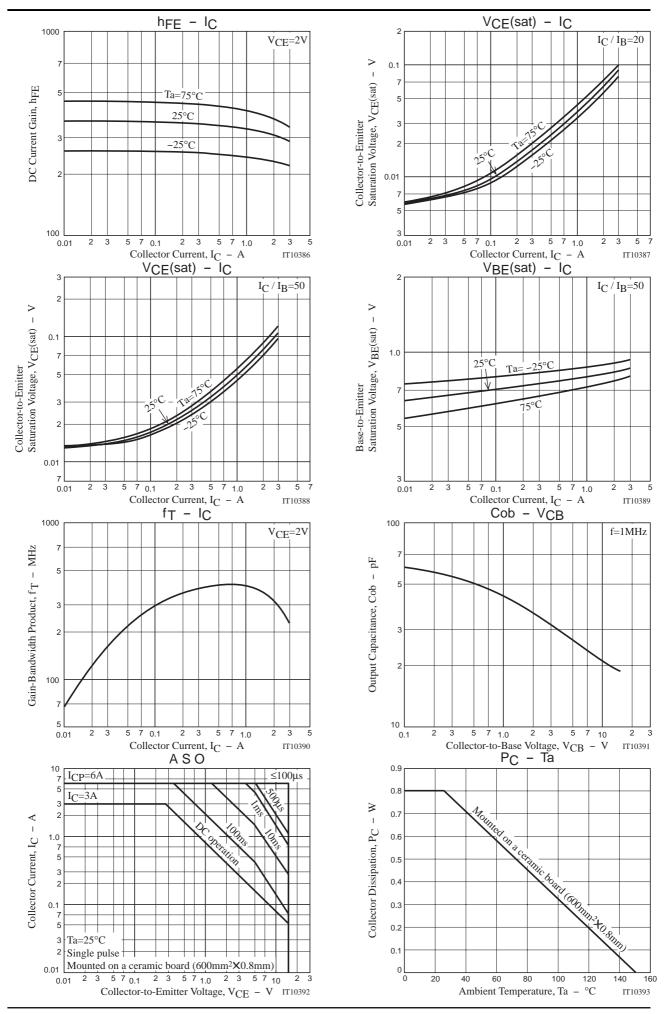
## **Switching Time Test Circuit**



$$I_{C}=20I_{B1}=-20I_{B2}=1.5A$$







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